NSN 5961-00-425-0633



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-425-0633 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **End Application:** Jforrestal class cv; iwo jima class lph; ticonderoga class cg (47); emory s. Land class as; deep submergence systems programs (dssp); tarawa class lha; wasp class lhd; nimitz class cvn; sturgeon class ssn (637) **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 1.00 amperes source cutoff current and 3.00 amperes source cutoff current

Power Rating Per Characteristic:

35.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Weapon system essential; junction pattern arrangement: npn

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Specification Data:

80131-release5676 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0